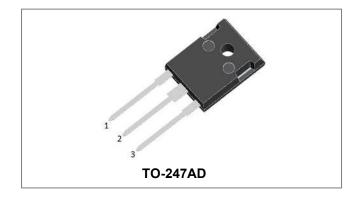






40CPQ200 SCHOTTKY RECTIFIER



Features

- 175 °C T_J operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- · Additional testing can be offered upon request

Circuit Diagram



Applications

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage	$V_{RRM} \ V_{RWM}$	-	200	V
DC Blocking Voltage	V_R			
Average Rectified Forward Current	I _{F (AV)}	50% duty cycle @Tc=145°C, rectangular wave form	20(Per Leg) 40(Per Device)	Α
Peak One Cycle Non-Repetitive Surge Current(Per Leg)	I _{FSM}	8.3ms, Half Sine pulse, T _C = 25 °C	432	Α

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop	V _{F1}	@ 20A, Pulse, T _J = 25 °C	0.80	0.90	V
(Per Leg)*	V_{F2}	@ 20A, Pulse, T _J = 125 °C	0.63	0.74	V
Reverse Current (Per Leg)*	I _{R1}	@V _R = rated V _R , T _J = 25 °C	0.0003	1.5	mA
	I _{R2}	@V _R = rated V _R , T _J = 125 °C	0.3	15.0	mA
Junction Capacitance(Per Leg)	Ст	$@V_R = 5V, T_C = 25 ^{\circ}C, f_{SIG} = 1MHz$	500	600	pF
Voltage Rate of Change	dv/dt	-	-	10,000	V/μs

 $^{^{*}}$ Pulse width < 300 μ s, duty cycle < 2%





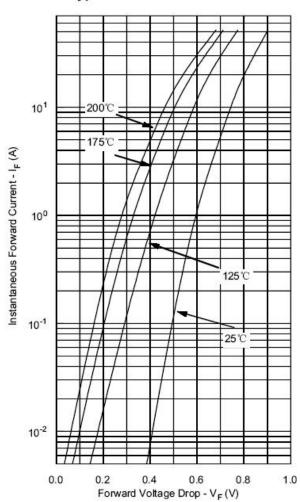


Thermal-Mechanical Specifications:

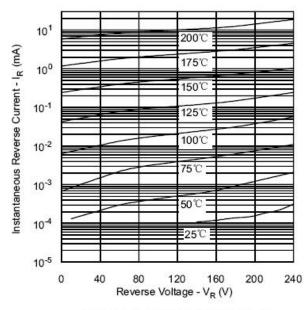
Characteristics	Symbol	Condition	Specification	Units	
Junction Temperature	TJ	-	-55 to +175	°C	
Storage Temperature	T _{stg}	-	-55 to +175	°C	
Typical Thermal Resistance Junction to	В.	DC operation	0.63 (per leg)	°C/W	
Case	R _{⊎JC}	DC operation	0.31 (per device)	C/VV	
Typical Thermal Resistance, case to Heat Sink	$R_{ heta cs}$	Mounting surface, smooth and greased	0.24	°C/W	
Approximate Weight	wt	-	6.28	g	
Case Style	TO-247AD				

Ratings and Characteristics Curves

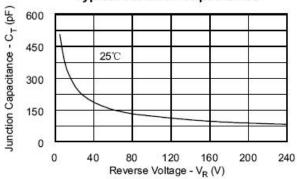
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



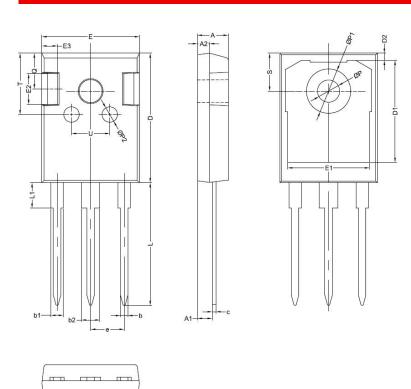
- China Germany Korea Singapore United States
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Mechanical Dimensions TO-247AD



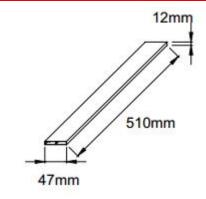
CVMDOL	Millimeters			
SYMBOL	MIN.	TYP.	MAX.	
Α	4.80	5.00	5.20	
A1	2.20	2.41	2.61	
A2	1.90	2.00	2.10	
b	1.10	1.20	1.40	
b1	1.80	2.00	2.20	
b2	2.80	3.00	3.20	
С	0.50	0.60	0.75	
D	20.30	21.00	21.20	
D1		16.55		
D2 E		1.20		
E	15.45	15.80	16.00	
E1		13.30		
E2		5.00		
E3		2.50		
е		5.44		
L	19.42	19.92	20.70	
L1		4.13		
Р	3.50	3.60	3.70	
P1	7.1		7.40	
P2		2.50		
Q		5.80		
Q S T	6.05	6.15	6.25	
T		10.00		
U		6.20		

Ordering Information:

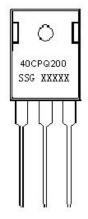
Device	Package	Shipping
40CPQ200	TO-247AD(Pb-Free)	25pcs / tube

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Tube Specification



Marking Diagram



Where XXXXX is YYWWL

40 = Forward Current (40A)
C = Configuration
PQ = Device Type

PQ = Device Type 200 = Reverse Voltage (200V) SSG = SSG

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •







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